FK350601

Silicon N-channel MOS FET

For switching circuits

■ Overview

FK350601 is N-channel small signal MOS FET employed small size surface mounting package.

■ Features

- Low drain-source ON resistance: $R_{DS(on)}$ typ. = 6 Ω (V_{GS} = 4.0 V)
- High-speed switching
- Small size surface mounting package: SMini3-F2-B
- Contributes to miniaturization of sets, reduction of component count.
- Eco-friendly Halogen-free package

■ Packaging

Embossed type (Thermo-compression sealing): 3000 pcs / reel (standard)

■ Absolute Maximum Ratings T_a = 25°C

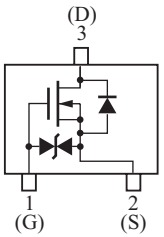
Parameter	Symbol	Rating	Unit
Drain-source surrender voltage	V_{DSS}	60	V
Gate-source surrender voltage	V_{GSS}	±12	V
Drain current	I_D	100	mA
Peak drain current	I_{DP}	200	mA
Power dissipation	P_D	150	mW
Channel temperature	T_{ch}	150	°C
Storage temperature	T_{stg}	–55 to +150	°C

■ Package

- Code
  SMini3-F2-B
- Pin Name
  1: Gate
  2: Source
  3: Drain

■ Marking Symbo: CV

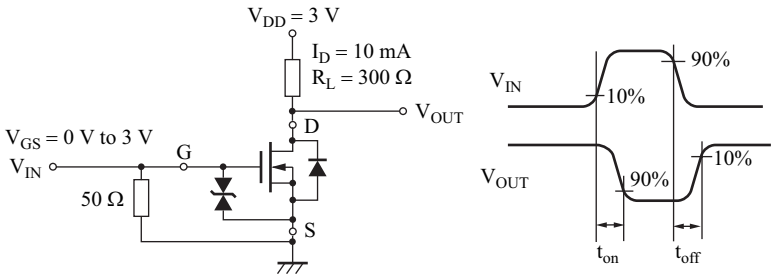
■ Internal Connection



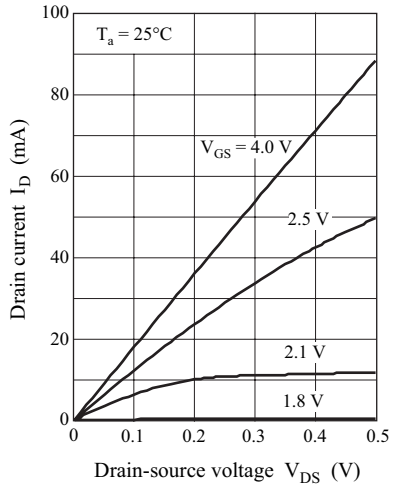
■ Electrical Characteristics T_a = 25°C±3°C

Parameter	Symbol	Conditions	Min	Typ	Max	Unit
Drain-source surrender voltage	V_{DSS}	I_D = 1.0 mA, V_{GS} = 0	60			V
Drain-source cutoff current	I_{DSS}	V_{DS} = 60 V, V_{GS} = 0			1.0	μA
Gate-source cutoff current	I_{GSS}	V_{GS} = ±10 V, V_{DS} = 0			±10	μA
Gate threshold voltage	V_{TH}	I_D = 1.0 μA, V_{DS} = 3 V	0.9	1.2	1.5	V
Drain-source ON resistance	$R_{DS(on)}$	I_D = 10 mA, V_{GS} = 2.5 V		8	15	Ω
		I_D = 10 mA, V_{GS} = 4.0 V		6	12	Ω
Forward transfer admittance	$\|Y_{fs}\|$	I_D = 10 mA, V_{DS} = 3 V, f = 1 MHz	20	60		ms
Short-circuit input capacitance (Common source)	C_{iss}	V_{DS} = 3 V, V_{GS} = 0, f = 1 MHz		12		pF
Short-circuit output capacitance (Common source)	C_{oss}			7		pF
Reverse transfer capacitance (Common source)	C_{rss}			3		pF
Turn-on time *	t_{on}	V_{DD} = 3 V, V_{GS} = 0 V to 3 V, I_D = 10 mA		100		ns
Turn-off time *	t_{off}	V_{DD} = 3 V, V_{GS} = 3 V to 0 V, I_D = 10 mA		100		ns

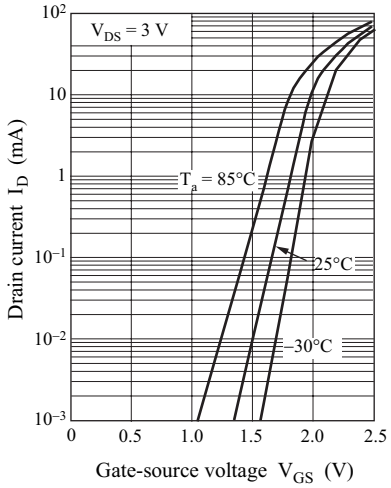
Note) 1. Measuring methods are based on JAPANESE INDUSTRIAL STANDARD JIS C 7030 measuring methods for transistors.
2. *: Test circuit



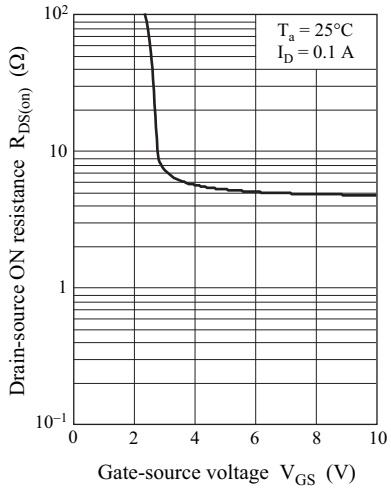
I_D — V_{DS}



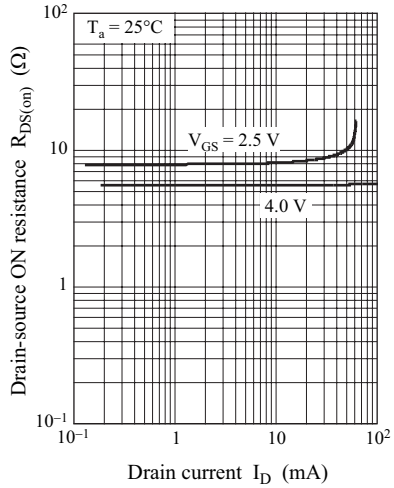
I_D — V_{GS}



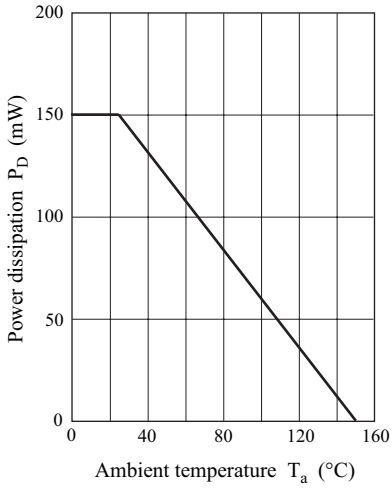
$R_{DS(on)}$ — V_{GS}



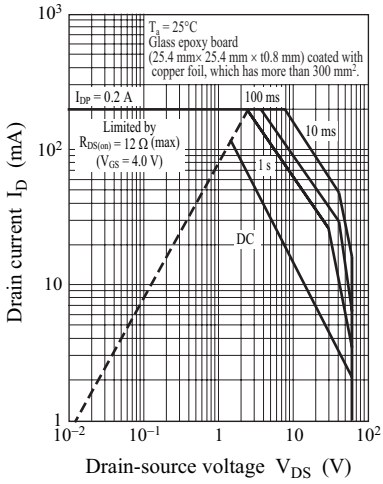
$R_{DS(on)}$ — I_D



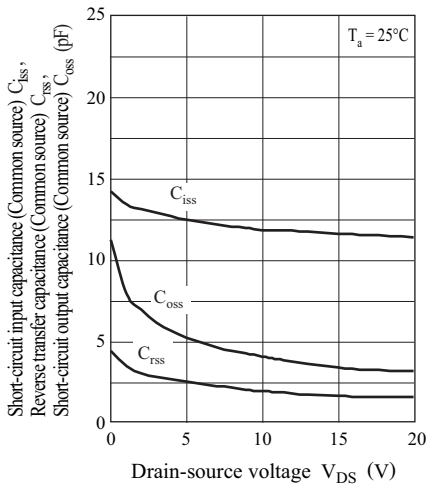
P_D — T_a



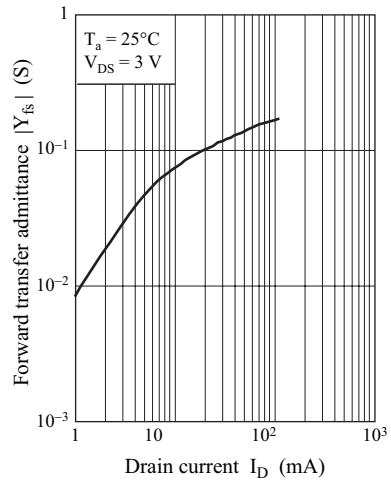
Safe operation area



C_{iss} , C_{rss} , C_{oss} — V_{DS}

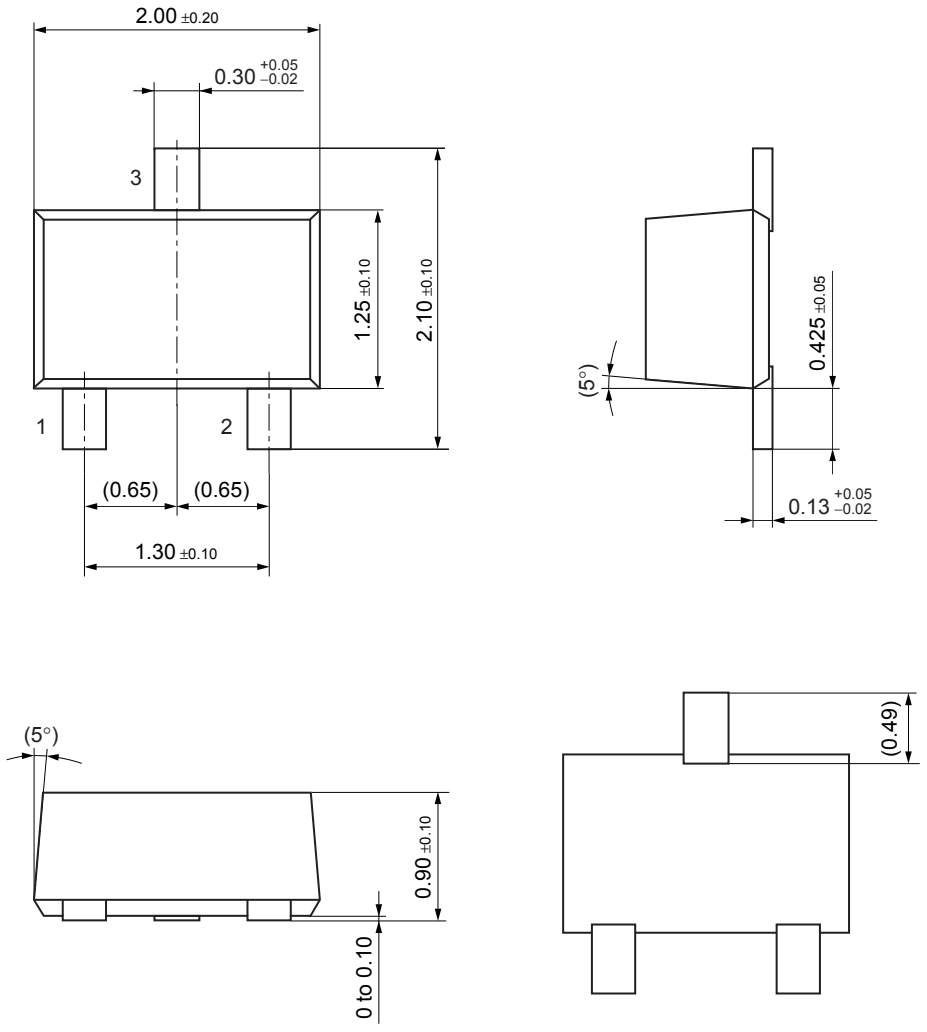


$|Y_{fs}|$ — I_D



SMini3-F2-B

Unit: mm



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